CEL

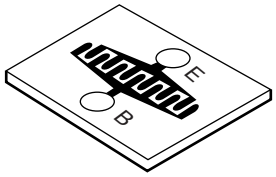
SILICON TRANSISTOR

NE680 SERIES

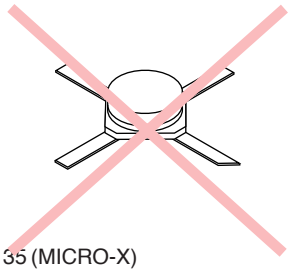
NPN SILICON HIGH FREQUENCY TRANSISTOR

FEATURES

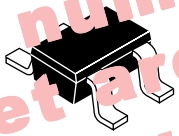
- **HIGH GAIN BANDWIDTH PRODUCT:** f_T = 10 GHz
- **LOW NOISE FIGURE:**
  1.7 dB at 2 GHz
  2.6 dB at 4 GHz
- **HIGH ASSOCIATED GAIN:**
  12.5 dB at 2 GHz
  8.0 dB at 4 GHz
- **EXCELLENT LOW VOLTAGE LOW CURRENT PERFORMANCE**



00 (CHIP)



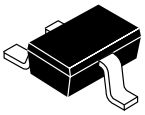
35 (MICRO-X)



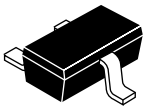
18 (SOT 343 STYLE)



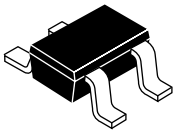
19 (3 PIN ULTRA SUPER MINI MOLD)



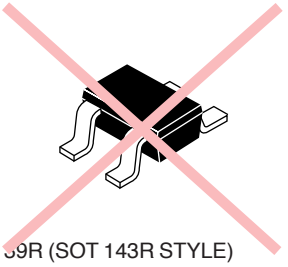
30 (SOT 323 STYLE)



33 (SOT 23 STYLE)



39 (SOT 143 STYLE)



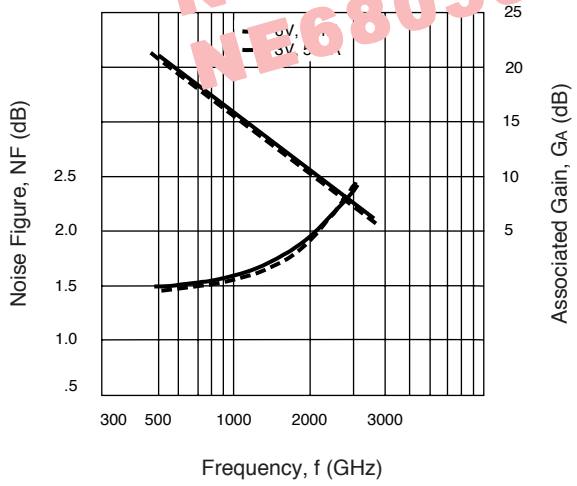
39R (SOT 143R STYLE)

DESCRIPTION

The NE680 series of NPN epitaxial silicon transistors is designed for low noise, high gain and low cost applications. Both the chip and micro-x versions are suitable for applications up to 6 GHz. The NE680 die is also available in six different low cost plastic surface mount package styles. The NE680's high f_T makes it ideal for low voltage/low current applications, down to as low as 0.5 V / 0.5 mA. IC max for the NE680 series is 35 mA. For higher current applications see the NE681 series.

PLEASE NOTE:
Obsolescing part numbers
recommended for new design.
Please call sales office for
details:
NE68035
NE68039R

NE68018
NOISE FIGURE & ASSOCIATED GAIN vs. FREQUENCY



ELECTRICAL CHARACTERISTICS (T_A = 25°C)

PART NUMBER EIAJ[1] REGISTERED NUMBER PACKAGE OUTLINE			NE68000 00 (CHIP)			NE68018 2SC5013 18			NE68019 2SC5008 19		
SYMBOLS	**PARAMETERS AND CONDITIONS**	**UNITS**	**MIN**	**TYP**	**MAX**	**MIN**	**TYP**	**MAX**	**MIN**	**TYP**	**MAX**
f_T	Gain Bandwidth Product at V_{CE} = 6 V, I_C = 10 mA	GHz		10			10			10	
NF	Noise Figure at V_{CE} = 6 V, I_C = 5 mA, f = 1 GHz	dB					1.6			1.7	
	f = 2 GHz	dB		1.7	2.4		1.8	3		1.9	
	f = 4 GHz	dB		2.6							
GNF	Associated Gain at V_{CE} = 6 V, I_C = 5 mA,										
	f = 1 GHz	dB					14			13.5	
	f = 2 GHz	dB		12.5			10.2			9.6	
	f = 4 GHz	dB		8							
MAG	Maximum Available Gain at V_{CE} = 6 V, I_C = 10 mA										
	f = 1 GHz	dB		18.5			19			18.5	
	f = 2 GHz	dB		16.2			12.7			11.8	
	f = 4 GHz	dB		10.2			8.2			7.3	
$\|S_{21E}\|^2$	Insertion Power Gain at V_{CE} = 6 V, I_C = 10 mA,										
	f = 1 GHz	dB		17			15.5			15	
	f = 2 GHz	dB	10.5	12.5		7.5	9.8			9.2	
	f = 4 GHz	dB		7.5			4.6			4.4	
h_{FE}	Forward Current Gain[2] at V_{CE} = 6 V, I_C = 10 mA		50	100	250	50	100	250			
	V_{CE} = 3 V, I_C = 5 mA								80		160
I_{CBO}	Collector Cutoff Current at V_{CB} = 10 V, I_E = 0 mA	μA			1.0			1.0			1.0
I_{EBO}	Emitter Cutoff Current at V_{EB} = 1V, I_C = 0 mA	μA			1.0			1.0			1.0
C_{RE}[3]	Feedback Capacitance at V_{CB} = 1 V, I_E = 0 mA, f = 1 MHz	pF					0.3	0.7		0.3	0.7
P_T	Total Power Dissipation	mW			400			150			100
$R_{TH\ (J\text{-}A)}$	Thermal Resistance (Junction to Ambient)	°C/W						833			1000
$R_{TH\ (J\text{-}C)}$	Thermal Resistance (Junction to Case)	°C/W			120			200			200

ELECTRICAL CHARACTERISTICS (T_A = 25°C)

PART NUMBER EIAJ[1] REGISTERED NUMBER PACKAGE OUTLINE			NE68030 2SC4228 30			NE68033 2SC3585 33			NE68035 2SC3587 35			NE68039/39R 2SC4095 39		
SYMBOLS	**PARAMETERS AND CONDITIONS**	**UNITS**	**MIN**	**TYP**	**MAX**	**MIN**	**TYP**	**MAX**	**MIN**	**TYP**	**MAX**	**MIN**	**TYP**	**MAX**
f_T	Gain Bandwidth Product at V_{CE} = 6 V, I_C = 10 mA	GHz		10			10			10			10	
NF	Noise Figure at V_{CE} = 6 V, I_C = 5 mA, f = 1 GHz	dB		1.5			1.6							
	f = 2 GHz	dB		1.7			1.8	3.0		1.7	2.4		1.7	2.5
	f = 4 GHz	dB		2.9			2.1			2.6			2.6	
GNF	Associated Gain at V_{CE} = 6 V, I_C = 5 mA,													
	f = 1 GHz	dB		12.5			11.0							
	f = 2 GHz	dB		9.4			9.0			12.5			11	
	f = 4 GHz	dB		5.3			4.2			8			6.5	
MAG	Maximum Available Gain at V_{CE} = 6 V, I_C = 10 mA													
	f = 1 GHz	dB		17			17			18.5			18	
	f = 2 GHz	dB		10.9			10.9			16.2			12.4	
	f = 4 GHz	dB		6.8			6.7			10.2			8.7	
$\|S_{21E}\|^2$	Insertion Power Gain at V_{CE} = 6 V, I_C = 10 mA,													
	f = 1 GHz	dB		13.5			13			17			14.5	
	f = 2 GHz	dB		8.5			6.7		10.5	12.5			9.6	
	f = 2 GHz	dB		3.6			3.7			7.5			4.9	
h_{FE}	Forward Current Gain[2] at V_{CE} = 6 V, I_C = 10 mA					50	100	250	50	100	250	50	100	250
	V_{CE} = 3 V, I_C = 5 mA		50	100	250									
I_{CBO}	Collector Cutoff Current at V_{CB} = 10 V, I_E = 0 mA	μA			1.0			1.0			1.0			1.0
I_{EBO}	Emitter Cutoff Current at V_{EB} = 1V, I_C = 0 mA	μA			1.0			1.0			1.0			1.0
C_{re}[3]	Feedback Capacitance at													
	V_{CB} = 3V, I_E = 0 mA, f = 1 MHz	pF		0.3	0.7									
	V_{CE} = 10 V, I_E = 0 mA, f = 1 MHz	pF					0.3	0.8		0.2	0.7		0.25	0.8
P_T	Total Power Dissipation	mW			150			200			290			200
$R_{TH\ (J\text{-}A)}$	Thermal Resistance (Junction to Ambient)	°C/W			833			620			550			620
$R_{TH\ (J\text{-}C)}$	Thermal Resistance (Junction to Case)	°C/W			200			200			200			200

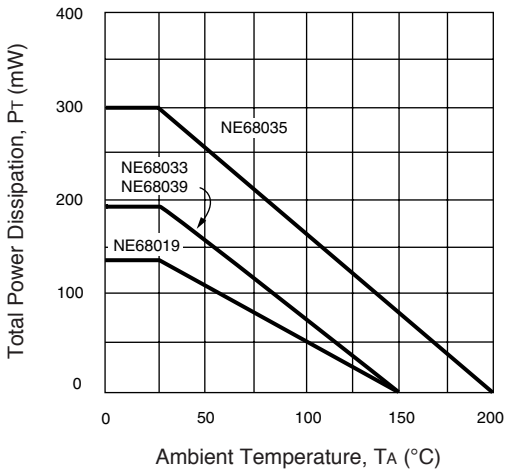
Notes:
1. Electronic Industrial Association of Japan.
2. Pulsed measurement, PW≤350 μs, duty cycle ≤2%.
3. The emitter terminal should be connected to the ground terminal of the 3 terminal capacitance bridge.

ABSOLUTE MAXIMUM RATINGS[1] (T_A = 25°C)

SYMBOLS	PARAMETERS	UNITS	RATINGS
V_{CBO}	Collector to Base Voltage	V	20
V_{CEO}	Collector to Emitter Voltage	V	10
V_{EBO}	Emitter to Base Voltage	V	1.5
I_C	Collector Current	mA	35
T_J	Junction Temperature	°C	150[2]
T_{STG}	Storage Temperature	°C	-65 to +150

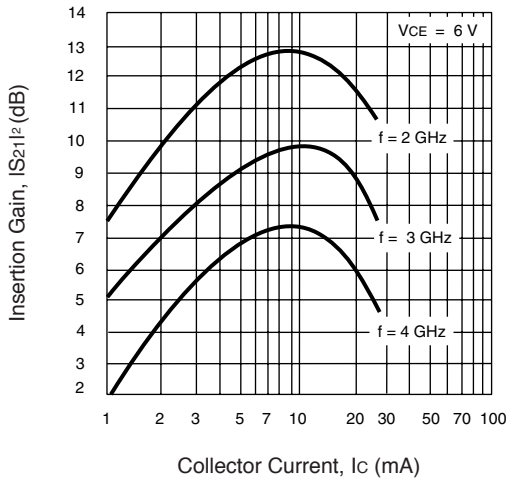
Notes:
1. Operation in excess of any one of these parameters may result in permanent damage.
2. Maximum T_J for the NE68035 is 200°C.

DC POWER DERATING CURVES

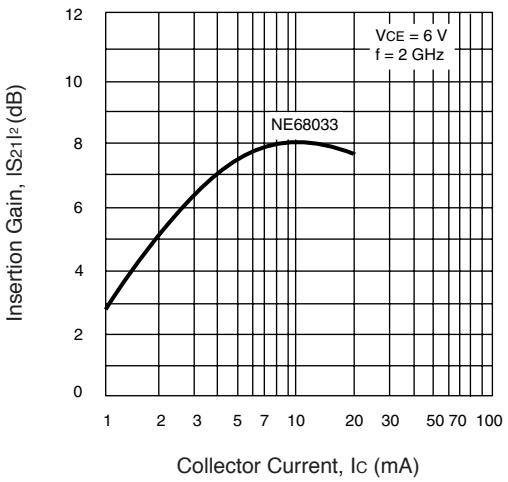


TYPICAL PERFORMANCE CURVES (T_A = 25°C)

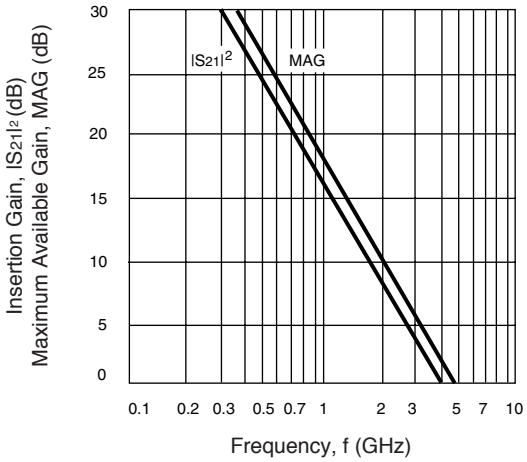
NE68035
INSERTION GAIN vs.
COLLECTOR CURRENT



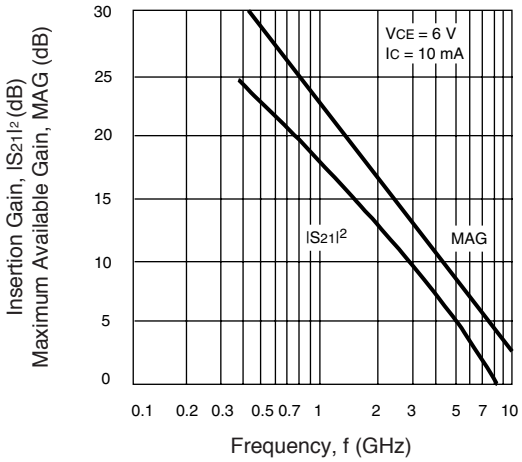
NE68033
INSERTION GAIN vs.
COLLECTOR CURRENT



NE68039
FORWARD INSERTION GAIN
AND MAXIMUM AVAILABLE
GAIN vs. FREQUENCY

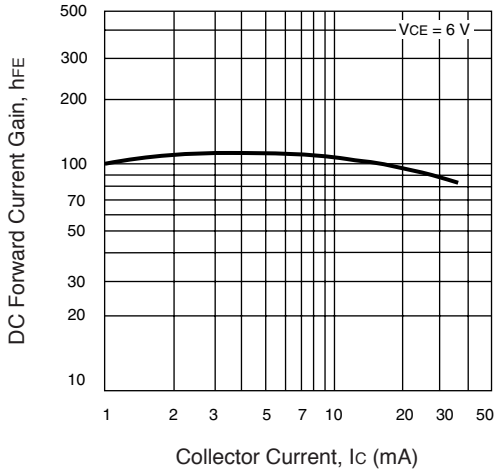


NE68035
FORWARD INSERTION GAIN
AND MAXIMUM AVAILABLE
GAIN vs. FREQUENCY

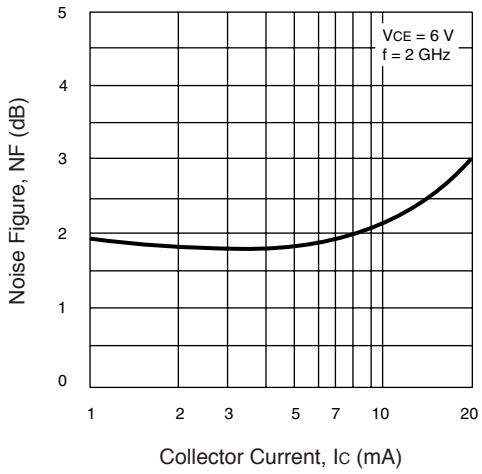


TYPICAL PERFORMANCE CURVES (TA = 25°C)

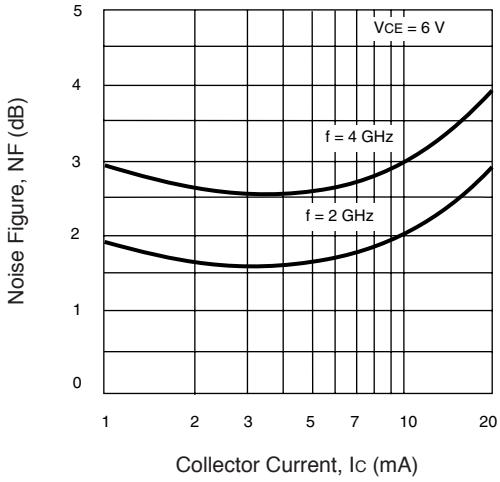
FORWARD CURRENT GAIN vs. COLLECTOR CURRENT



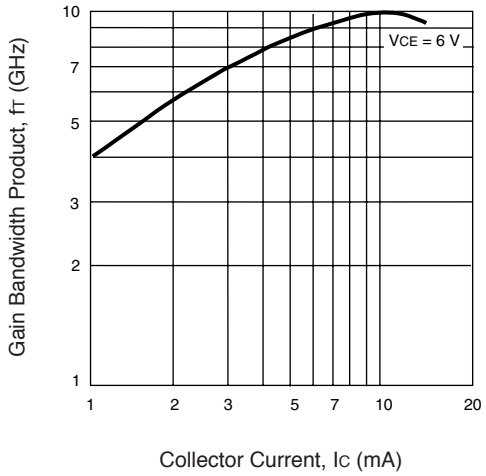
NE68033 NOISE FIGURE vs. COLLECTOR CURRENT



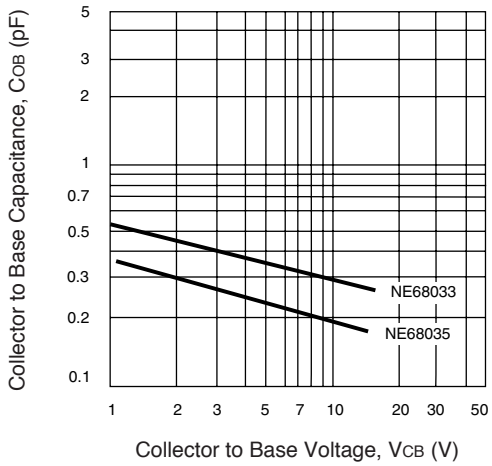
NE68035 NOISE FIGURE vs. COLLECTOR CURRENT



GAIN BANDWIDTH PRODUCT vs. COLLECTOR CURRENT



COLLECTOR TO BASE CAPACITANCE vs. COLLECTOR TO BASE VOLTAGE



NE68018
TYPICAL NOISE PARAMETERS (T_A = 25°C)

FREQ. (MHz)	NF_{OPT} (dB)	G_A (dB)	Γ_{OPT} MAG	Γ_{OPT} ANG	Rn/50
V_{CE} = 3 V, I_C = 5 mA					
500	1.45	20.74	0.46	22	0.41
800	1.50	17.44	0.39	44	0.32
1000	1.55	15.79	0.34	54	0.29
2000	1.90	9.96	0.24	76	0.26
3000	2.40	7.26	0.16	130	0.12
V_{CE} = 6 V, I_C = 5 mA					
500	1.5	21.20	.47	21	0.44
800	1.6	17.50	.38	36	0.31
1000	1.6	15.63	.44	47	0.43
2000	2.1	10.20	.32	81	0.27
3000	2.4	7.49	.19	125	0.14

NE68019
TYPICAL NOISE PARAMETERS (T_A = 25°C)

FREQ. (MHz)	NF_{OPT} (dB)	G_A (dB)	Γ_{OPT} MAG	Γ_{OPT} ANG	Rn/50
V_{CE} = 3 V, I_C = 5mA					
500	1.36	19.2	0.52	18	0.47
800	1.47	15.7	0.48	33	0.33
1000	1.55	14.0	0.46	41	0.31
1500	1.71	11.0	0.42	58	0.27
2000	1.88	9.0	0.32	75	0.22
2500	2.06	7.4	0.27	86	0.18
3000	2.29	6.0	0.22	103	0.12
V_{CE} = 6 V, I_C = 5 mA					
500	1.36	19.44	0.56	16	0.50
800	1.47	15.86	0.54	30	0.36
1000	1.55	14.16	0.52	39	0.33
1500	1.71	11.15	0.48	58	0.30
2000	1.88	9.49	0.36	77	0.27
2500	2.06	7.89	0.30	88	0.23
3000	2.29	6.74	0.24	103	0.17

NE68035
TYPICAL NOISE PARAMETERS (T_A = 25°C)

FREQ. (MHz)	NF_{OPT} (dB)	G_A (dB)	Γ_{OPT} MAG	Γ_{OPT} ANG	Rn/50
V_{CE} = 6 V, I_C = 5 mA					
1000	1.2	19.21	0.30	65	0.37
2000	1.7	14.49	0.20	155	0.30
4000	2.6	9.12	0.22	-128	0.33

NE68030
TYPICAL NOISE PARAMETERS (T_A = 25°C)

FREQ. (MHz)	NF_{OPT} (dB)	G_A (dB)	Γ_{OPT} MAG	Γ_{OPT} ANG	Rn/50
V_{CE} = 2.5 V, I_C = 3 mA					
500	1.32	12.79	0.79	21	1.60
800	1.48	12.59	0.72	40	1.43
1000	1.58	11.35	0.69	52	1.08
1500	1.82	5.87	0.64	64	0.92
2000	2.12	3.48	0.59	78	0.75
V_{CE} = 6 V, I_C = 5 mA					
1000	1.52	16.93	0.46	126	0.15
2000	1.76	10.70	0.37	-159	0.11
3000	2.25	7.56	0.36	-132	0.14
4000	2.92	5.82	0.35	-115	0.16

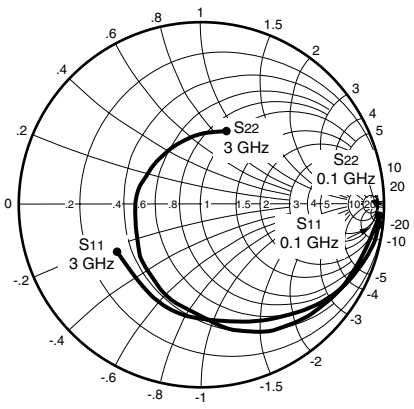
NE68033
TYPICAL NOISE PARAMETERS (T_A = 25°C)

FREQ. (MHz)	NF_{OPT} (dB)	G_A (dB)	Γ_{OPT} MAG	Γ_{OPT} ANG	Rn/50
V_{CE} = 2.5 V, I_C = 3 mA					
500	1.10	18.26	0.65	21	0.56
800	1.20	14.56	0.60	32	0.42
1000	1.27	13.26	0.52	43	0.39
1500	1.43	9.80	0.47	48	0.36
2000	1.64	7.76	0.39	53	0.32
V_{CE} = 6 V, I_C = 5 mA					
500	1.35	19.25	0.60	17	0.60
1000	1.45	14.20	0.45	33	0.48
2000	1.70	9.18	0.22	42	0.45
3000	2.10	6.60	0.11	-4	0.40
4000	2.55	5.22	0.18	-63	0.47

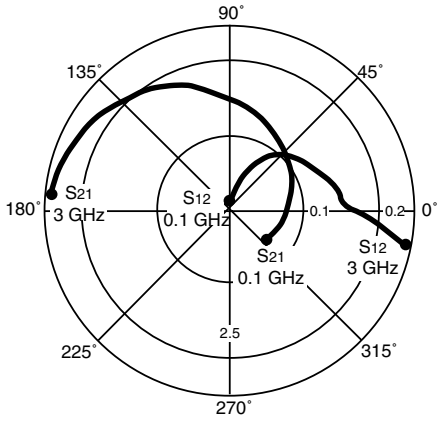
NE68039
TYPICAL NOISE PARAMETERS (T_A = 25°C)

FREQ. (MHz)	NF_{OPT} (dB)	G_A (dB)	Γ_{OPT} MAG	Γ_{OPT} ANG	Rn/50
V_{CE} = 2.5 V, I_C = 3 mA					
500	1.14	19.29	0.54	18	0.41
800	1.21	15.55	0.47	28	0.35
1000	1.26	14.04	0.42	39	0.29
1500	1.40	10.98	0.31	55	0.25
2000	1.62	9.34	0.16	97	0.19
V_{CE} = 6 V, I_C = 5 mA					
500	1.5	20.60	0.52	3	0.52
1000	1.6	15.91	0.38	29	0.40
2000	1.7	10.82	0.18	81	0.26
3000	2.1	8.49	0.17	-158	0.29
4000	2.6	7.21	0.40	-116	0.31

TYPICAL COMMON EMITTER SCATTERING PARAMETERS (T_A = 25°C)



Coordinates in Ohms
Frequency in GHz
(V_{CE} = 2.5 V, I_C = 1 mA)



NE68018

V_{CE} = 2.5 V, I_C = 1 mA

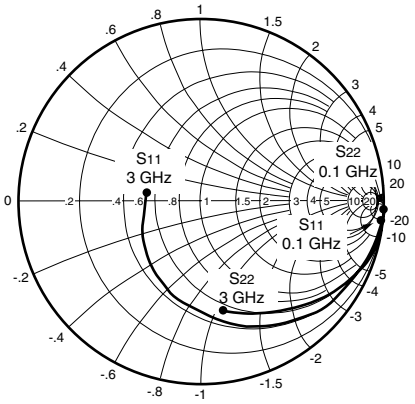
FREQUENCY	S11		S21		S12		S22		K	MAG[1]
(MHz)	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG		(dB)
100	.972	-9.4	3.605	170.2	.017	81.6	.995	-3.5	0.12	23.3
400	.907	-34.2	3.315	146.5	.061	65.5	.966	-20.2	0.19	17.4
800	.778	-65.1	2.897	118.1	.104	45.6	.874	-37.5	0.35	14.4
1000	.706	-78.9	2.678	105.8	.114	38.1	.841	-44.3	0.42	13.7
1500	.561	-111.0	2.173	78.7	.135	21.4	.755	-58.4	0.65	12.1
2000	.457	-139.5	1.800	56.6	.147	11.8	.712	-70.4	0.82	10.9
2500	.389	-166.6	1.545	37.3	.145	4.8	.668	-80.5	1.08	8.5
3000	.356	167.0	1.358	20.7	.150	2.4	.651	-90.6	1.20	6.9
V_{CE} = 2.5 V, I_C = 3 mA										
100	.884	-12.9	9.246	166.6	.018	77.7	.964	-8.5	0.19	27.1
400	.729	-52.2	7.715	132.3	.056	58.5	.864	-27.8	0.34	21.4
800	.507	-90.1	5.509	101.2	.073	41.2	.704	-43.7	0.63	18.8
1000	.430	-105.8	4.722	89.8	.087	38.3	.657	-48.3	0.71	17.3
1500	.312	-138.0	3.398	66.8	.110	35.6	.591	-58.8	0.88	14.9
2000	.259	-167.5	2.645	48.2	.120	27.1	.561	-69.0	1.07	11.8
2500	.231	164.8	2.189	31.5	.137	23.2	.544	-78.5	1.15	9.7
3000	.223	139.5	1.876	16.9	.165	18.5	.539	-87.7	1.13	8.4
V_{CE} = 6 V, I_C = 5 mA										
100	.838	-17.7	13.662	163.3	.012	80.3	.965	-9.5	0.13	30.6
400	.610	-61.4	10.216	124.3	.037	61.1	.819	-28.3	0.42	24.4
800	.381	-99.4	6.605	94.4	.063	48.9	.661	-40.1	0.73	20.2
1000	.314	-114.8	5.516	83.9	.067	47.8	.630	-43.7	0.85	19.2
1500	.223	-149.1	3.855	63.0	.092	43.1	.587	-54.1	0.97	16.2
2000	.188	-178.0	2.963	45.9	.112	34.0	.569	-63.6	1.07	12.6
2500	.185	153.8	2.417	30.3	.130	33.0	.567	-72.1	1.10	10.8
3000	.173	129.0	2.063	16.4	.155	23.5	.563	-82.5	1.10	9.3

Note:
1.Gain Calculations:

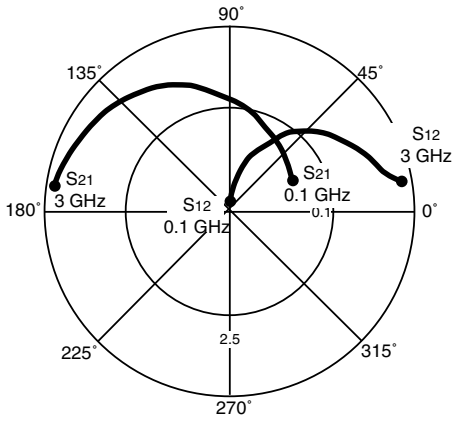
$MAG = \frac{|S_{21}|}{|S_{12}|}\left(K \pm \sqrt{K^2 - 1}\right)$. When $K \leq 1$, MAG is undefined and MSG values are used. $MSG = \frac{|S_{21}|}{|S_{12}|}$, $K = \frac{1 + |\Delta|^2 - |S_{11}|^2 - |S_{22}|^2}{2\,|S_{12}\,S_{21}|}$, $\Delta = S_{11}\,S_{22} - S_{21}\,S_{12}$

MAG = Maximum Available Gain
MSG = Maximum Stable Gain

TYPICAL COMMON EMITTER SCATTERING PARAMETERS (T_A = 25°C)



Coordinates in Ohms
Frequency in GHz
(V_{CE} = 2.5 V, I_C = 1 mA)



NE68019

V_{CE} = 2.5 V, I_C = 1 mA

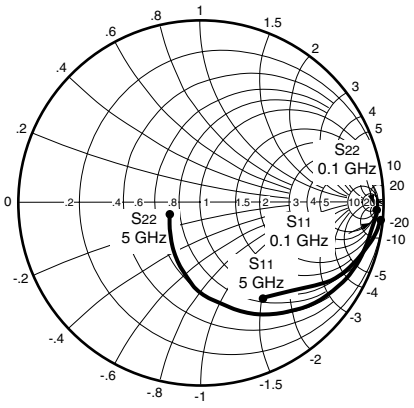
FREQUENCY	S_{11}		S_{21}		S_{12}		S_{22}		K	MAG[1]
(MHz)	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG		(dB)
100	.971	-9.9	3.456	169.4	.017	84.6	0.996	-6.2	0.03	23.1
400	.905	-34.9	3.207	145.8	.064	66.7	0.961	-20.2	0.17	17.0
800	.774	-65.1	2.751	117.3	.110	46.1	0.869	-36.6	0.37	14.0
1000	.706	-78.0	2.512	105.2	.126	38.1	0.829	-43.1	0.46	13.0
1500	.564	-106.1	2.043	80.0	.146	25.4	0.751	-54.7	0.68	11.5
2000	.453	-130.7	1.721	59.1	.155	17.5	0.695	-63.8	0.90	10.5
2500	.364	-156.6	1.497	40.9	.162	13.5	0.658	-71.6	1.08	7.9
3000	.303	174.5	1.355	24.5	.176	9.9	0.624	-79.9	1.19	6.2
V_{CE} = 2.5 V, I_C = 3 mA										
100	.905	-15.3	9.292	165.2	.018	81.0	.968	-9.4	0.10	27.1
400	.726	-52.5	7.492	131.0	.057	60.9	.848	-28.7	0.34	21.2
800	.505	-87.4	5.221	100.5	.083	46.2	.684	-42.7	0.63	18.0
1000	.428	-100.0	4.439	89.5	.093	42.5	.638	-46.9	0.75	16.8
1500	.302	-126.3	3.211	67.8	.116	36.3	.582	-54.4	0.95	14.4
2000	.223	-149.5	2.520	50.2	.138	33.0	.551	-61.4	1.08	10.9
2500	.172	-177.0	2.100	34.7	.163	28.4	.532	-67.6	1.13	8.9
3000	.149	150.7	1.831	20.4	.191	22.6	.507	-75.5	1.15	7.5
V_{CE} = 6 V, I_C = 5 mA										
100	.849	-18.0	13.629	162.0	.018	85.2	.949	-9.6	0.11	28.8
400	.613	-60.8	9.820	123.1	.050	60.7	.789	-29.4	0.45	22.9
800	.386	-93.9	6.206	93.8	.067	49.2	.639	-39.2	0.79	19.7
1000	.317	-105.5	5.157	83.9	.079	47.3	.607	-42.2	0.87	18.1
1500	.215	-128.5	3.615	64.1	.102	43.3	.575	-49.1	1.02	14.6
2000	.149	-149.7	2.786	47.9	.127	39.9	.563	-55.7	1.09	11.6
2500	.103	-178.6	2.298	33.5	.156	34.0	.552	-62.3	1.10	9.80
3000	.092	143.3	1.989	20.1	.185	28.9	.537	-70.2	1.10	8.40

Note:
1.Gain Calculations:

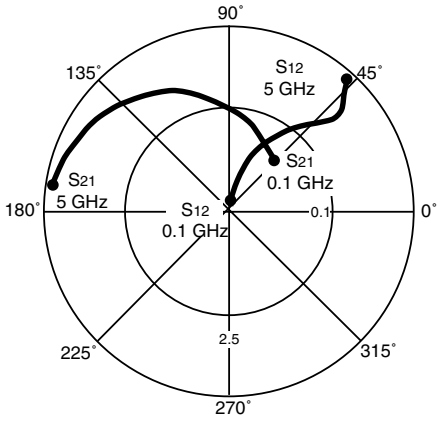
MAG = $\frac{|S_{21}|}{|S_{12}|}\left(K \pm \sqrt{K^2 - 1}\right)$. When K ≤ 1, MAG is undefined and MSG values are used. MSG = $\frac{|S_{21}|}{|S_{12}|}$, K = $\frac{1 + |\Delta|^2 - |S_{11}|^2 - |S_{22}|^2}{2\,|S_{12}\,S_{21}|}$, $\Delta = S_{11}\,S_{22} - S_{21}\,S_{12}$

MAG = Maximum Available Gain
MSG = Maximum Stable Gain

TYPICAL COMMON EMITTER SCATTERING PARAMETERS (T_A = 25°C)



Coordinates in Ohms
Frequency in GHz
(V_{CE} = 2.5 V, I_C = 1 mA)



NE68030

V_{CE} = 2.5 V, I_C = 1 mA

FREQUENCY	S_{11}		S_{21}		S_{12}		S_{22}		K	MAG[1]
(MHz)	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG		(dB)
100	.958	-8.2	3.592	171.5	.018	82.5	.988	-4.2	0.11	23.0
400	.907	-31.4	3.325	148.1	.065	70.1	.949	-16.3	0.21	17.1
800	.752	-57.5	2.807	121.4	.107	55.3	.860	-28.7	0.42	14.2
1000	.672	-68.0	2.541	110.8	.122	50.3	.814	-33.2	0.53	13.2
1500	.500	-90.6	2.058	89.1	.147	43.4	.727	-40.7	0.77	11.5
2000	.371	-108.7	1.705	71.5	.157	41.1	.687	-46.7	0.99	10.4
2500	.257	-129.3	1.479	57.1	.173	43.5	.658	-51.7	1.13	7.1
3000	.172	-154.1	1.331	45.0	.194	46.5	.638	-56.6	1.18	5.8

V_{CE} = 2.5 V, I_C = 3 mA

100	.907	-14.6	9.563	166.7	.018	75.1	.983	-8.1	0.19	27.3
400	.706	-47.3	7.296	131.3	.056	64.8	.832	-23.2	0.43	21.1
800	.461	-72.5	4.915	103.2	.084	57.3	.687	-31.8	0.74	17.7
1000	.382	-80.6	4.154	93.9	.098	56.6	.646	-34.3	0.83	16.3
1500	.238	-95.8	2.979	76.9	.131	56.1	.585	-37.7	1.00	13.6
2000	.155	-101.6	2.324	62.8	.159	54.7	.579	-42.2	1.08	9.9
2500	.078	-107.6	1.940	51.3	.194	54.2	.570	-47.0	1.09	8.2
3000	.026	-102.4	1.679	41.5	.230	51.9	.561	-51.8	1.09	6.8

V_{CE} = 6 V, I_C = 10 mA

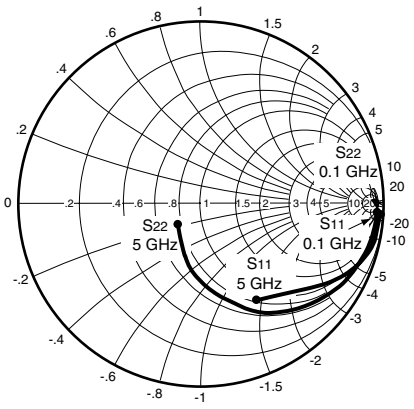
100	.769	-21.7	20.130	156.0	.015	80.5	.936	-10.5	0.25	31.3
400	.403	-60.5	11.063	113.0	.039	69.4	.679	-20.7	0.77	24.5
600	.281	-70.3	7.969	100.1	.052	70.5	.623	-21.3	0.91	21.9
800	.209	-75.2	6.153	91.4	.067	71.0	.594	-22.3	0.98	19.6
1000	.158	-77.4	4.995	84.2	.079	70.8	.582	-23.3	1.04	16.8
1200	.129	-81.3	4.190	78.8	.096	72.2	.564	-26.1	1.05	15.0
1400	.087	-81.5	3.651	74.3	.112	70.8	.551	-26.6	1.06	13.6
1600	.062	-77.2	3.247	69.3	.129	69.3	.556	-28.7	1.05	12.6
1800	.041	-71.7	2.915	64.9	.142	68.2	.555	-30.6	1.05	11.8
2000	.025	-76.9	2.655	60.6	.157	66.5	.555	-32.9	1.05	10.9
2500	.022	34.5	2.171	51.5	.192	63.8	.549	-38.7	1.05	9.2
3000	.048	59.7	1.874	43.0	.229	61.2	.542	-43.8	1.03	8.1
3500	.080	65.8	1.658	35.3	.270	58.0	.530	-50.4	1.01	7.3
4000	.126	68.2	1.514	28.0	.314	53.3	.514	-57.6	0.98	6.8
4500	.161	70.1	1.411	20.7	.357	49.4	.478	-66.2	0.97	6.0
5000	.232	68.1	1.330	13.9	.406	45.0	.426	-76.0	0.95	5.2

Note:
1.Gain Calculations:

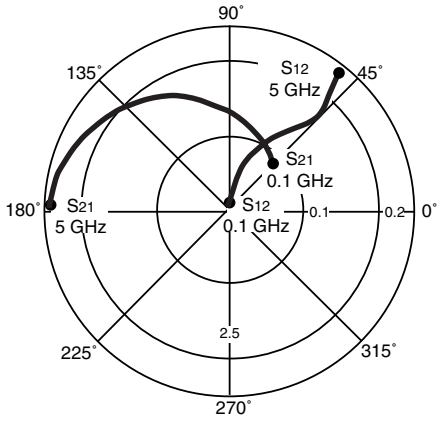
$MAG = \frac{|S_{21}|}{|S_{12}|}\left(K \pm \sqrt{K^2 - 1}\right)$. When $K \le 1$, MAG is undefined and MSG values are used. $MSG = \frac{|S_{21}|}{|S_{12}|}$, $K = \frac{1 + |\Delta|^2 - |S_{11}|^2 - |S_{22}|^2}{2\,|S_{12}\,S_{21}|}$, $\Delta = S_{11}\,S_{22} - S_{21}\,S_{12}$

MAG = Maximum Available Gain
MSG = Maximum Stable Gain

TYPICAL COMMON EMITTER SCATTERING PARAMETERS (T_A = 25°C)



Coordinates in Ohms
Frequency in GHz
(V_{CE} = 2.5 V, I_C = 1 mA)



NE68033

V_{CE} = 2.5 V, I_C = 1 mA

FREQUENCY	S11		S21		S12		S22		K	MAG[1]
(MHz)	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG		(dB)
100	.967	-8.2	3.635	170.6	.019	81.5	.990	-4.1	0.14	22.8
400	.903	-29.4	3.254	147.9	.069	71.0	.948	-16.8	0.23	16.7
800	.732	-53.1	2.758	121.3	.116	56.2	.846	-29.0	0.48	13.8
1000	.658	-62.8	2.508	110.3	.131	51.9	.801	-33.5	0.58	12.8
1500	.478	-83.0	2.043	88.2	.154	46.9	.715	-41.4	0.82	11.2
2000	.349	-100.5	1.708	71.1	.173	46.2	.663	-47.5	1.00	9.9
2500	.242	-114.6	1.507	56.5	.194	48.6	.633	-53.4	1.10	7.0
3000	.155	-136.7	1.371	44.6	.227	50.9	.609	-59.7	1.11	5.8

V_{CE} = 2.5 V, I_C = 3 mA

100	.906	-13.9	9.367	165.4	.019	84.5	.972	-7.4	0.1	26.9
400	.704	-43.9	7.037	130.3	.058	65.0	.821	-23.5	0.48	20.8
800	.448	-64.8	4.712	103.1	.093	60.4	.670	-31.2	0.78	17.0
1000	.370	-71.3	3.960	93.7	.106	59.8	.632	-33.1	0.88	15.7
1500	.241	-80.5	2.864	76.6	.144	59.3	.582	-37.1	1.00	13.0
2000	.167	-85.7	2.263	63.0	.181	58.0	.563	-41.8	1.05	9.6
2500	.104	-81.4	1.916	51.6	.221	56.3	.552	-47.0	1.06	7.9
3000	.065	-78.4	1.700	41.6	.264	53.4	.541	-53.3	1.03	7.0

V_{CE} = 6 V, I_C = 10 mA

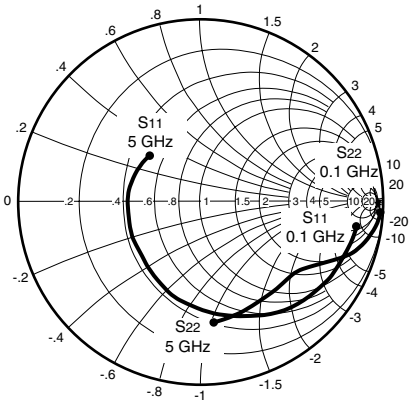
50	.817	-10.6	21.366	168.2	.006	85.7	.974	-5.5	0.13	35.5
100	.769	-21.7	20.130	156.0	.015	80.5	.936	-10.5	0.25	31.3
200	.628	-40.1	16.661	136.5	.024	71.6	.826	-17.6	0.48	28.4
400	.403	-60.5	11.063	113.0	.039	69.4	.679	-20.7	0.77	24.5
600	.281	-70.3	7.969	100.1	.052	70.5	.623	-21.3	0.91	21.9
800	.209	-75.2	6.153	91.4	.067	71.0	.594	-22.3	0.98	19.6
1000	.158	-77.4	4.995	84.2	.079	70.8	.582	-23.3	1.04	16.8
1200	.129	-81.3	4.190	78.8	.096	72.2	.564	-26.1	1.05	15.0
1400	.087	-81.5	3.651	74.3	.112	70.8	.551	-26.6	1.06	13.6
1600	.062	-77.2	3.247	69.3	.129	69.3	.556	-28.7	1.05	12.6
1800	.041	-71.7	2.915	64.9	.142	68.2	.555	-30.6	1.05	11.8
2000	.025	-76.9	2.655	60.6	.157	66.5	.555	-32.9	1.05	10.9
2500	.022	34.5	2.171	51.5	.192	63.8	.549	-38.7	1.05	9.2
3000	.048	59.7	1.874	43.0	.229	61.2	.542	-43.8	1.03	8.1
3500	.080	65.8	1.658	35.3	.270	58.0	.530	-50.4	1.01	7.3
4000	.126	68.2	1.514	28.0	.314	53.3	.514	-57.6	0.98	6.8
4500	.161	70.1	1.411	20.7	.357	49.4	.478	-66.2	0.97	6.0
5000	.232	68.1	1.330	13.9	.406	45.0	.426	-76.0	0.95	5.2

Note:
1.Gain Calculations:

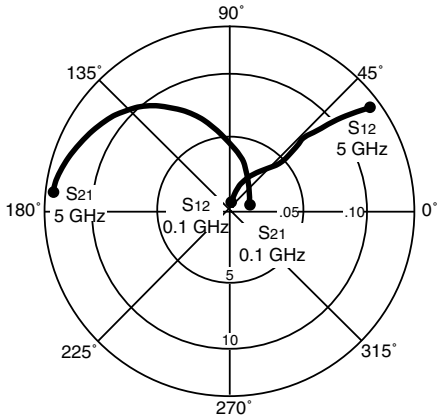
$$MAG = \frac{|S_{21}|}{|S_{12}|}\left(K \pm \sqrt{K^2 - 1}\right)$$. When $K \le 1$, MAG is undefined and MSG values are used. $$MSG = \frac{|S_{21}|}{|S_{12}|}$$, $$K = \frac{1 + |\Delta|^2 - |S_{11}|^2 - |S_{22}|^2}{2\,|S_{12}\,S_{21}|}$$, $\Delta = S_{11}\,S_{22} - S_{21}\,S_{12}$

MAG = Maximum Available Gain
MSG = Maximum Stable Gain

TYPICAL COMMON EMITTER SCATTERING PARAMETERS (T_A = 25°C)



Coordinates in Ohms
Frequency in GHz
(V_{CE} = 6 V, I_C = 5 mA)



NE68035

V_{CE} = 6 V, I_C = 5 mA

FREQUENCY	S11		S21		S12		S22		K	MAG[1]
(MHz)	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG		(dB)
100	.869	-13.4	12.862	167.5	.009	83.8	.989	-5.8	0.07	31.4
500	.682	-69.0	9.959	128.3	.034	55.9	.834	-22.2	0.36	24.6
1000	.518	-111.7	6.550	100.6	.047	45.2	.706	-30.0	0.64	21.4
1500	.440	-137.9	4.709	83.9	.056	43.5	.658	-35.4	0.85	19.3
2000	.414	-156.8	3.658	70.8	.064	43.2	.642	-41.5	0.98	17.6
2500	.400	-171.6	3.004	59.6	.073	43.2	.637	-48.0	1.04	14.9
3000	.392	175.7	2.527	49.3	.083	42.8	.639	-55.0	1.08	13.1
3500	.385	164.5	2.182	39.8	.093	41.9	.646	-62.2	1.10	11.8
4000	.382	155.2	1.973	30.9	.103	40.4	.654	-69.4	1.08	11.0
4500	.376	146.2	1.733	22.3	.114	38.9	.664	-76.7	1.07	10.3
5000	.372	137.8	1.575	14.0	.126	37.0	.675	-83.7	1.03	9.9

V_{CE} = 6 V, I_C = 10 mA

100	.766	-23.2	20.629	162.3	.008	75.9	.972	-8.0	0.16	33.9
500	.534	-96.2	12.610	115.8	.027	53.3	.746	-22.7	0.52	26.8
1000	.434	-138.0	7.284	91.5	.037	50.8	.649	-27.2	0.84	23.0
1500	.401	-160.0	5.035	77.3	.046	52.5	.625	-32.3	1.02	19.6
2000	.397	-174.9	3.852	65.7	.057	53.2	.619	-38.6	1.07	16.6
2500	.394	173.1	3.133	55.4	.068	52.7	.622	-45.5	1.09	14.8
3000	.396	162.7	2.626	45.8	.079	51.7	.627	-52.7	1.09	13.4
3500	.393	153.2	2.261	36.7	.091	50.0	.637	-60.1	1.07	12.3
4000	.394	145.2	2.000	28.2	.103	47.6	.648	-67.5	1.04	11.7
4500	.392	137.3	1.785	19.8	.115	45.3	.660	-75.0	1.01	11.3
5000	.391	129.4	1.619	11.7	.128	42.8	.672	-82.1	0.97	11.0

V_{CE} = 6 V, I_C = 20 mA

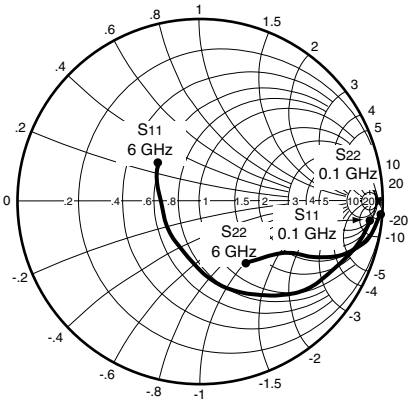
100	.593	-45.9	25.683	152.5	.008	73.6	.933	-9.6	0.20	35.3
500	.463	-132.6	11.309	103.7	.019	54.1	.713	-18.0	0.80	27.7
1000	.443	-163.8	6.056	83.9	.029	58.6	.672	-22.6	1.09	21.4
1500	.436	-178.8	4.124	71.6	.039	61.6	.664	-29.1	1.21	17.5
2000	.443	170.3	3.140	60.8	.051	62.0	.665	-36.5	1.20	15.2
2500	.448	160.8	2.547	50.9	.062	61.3	.670	-44.1	1.18	13.6
3000	.453	152.3	2.132	41.5	.074	60.0	.677	-52.0	1.13	12.4
3500	.454	144.1	1.832	32.5	.087	58.0	.687	-59.9	1.09	11.4
4000	.459	136.7	1.618	24.0	.099	55.4	.697	-67.8	1.03	11.1
4500	.460	129.2	1.441	15.7	.112	52.9	.708	-75.7	0.98	11.1
5000	.461	121.6	1.304	7.7	.127	50.2	.718	-83.1	0.92	10.1

Note:
1.Gain Calculations:

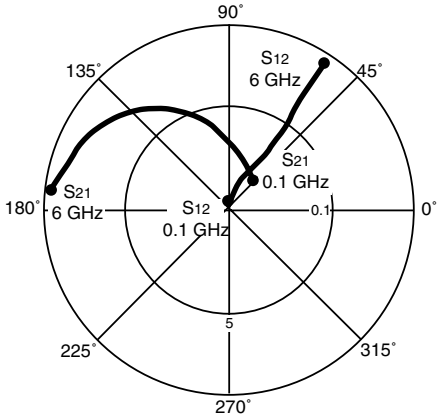
$MAG = \frac{|S_{21}|}{|S_{12}|}\left(K \pm \sqrt{K^2 - 1}\right)$. When $K \leq 1$, MAG is undefined and MSG values are used. $MSG = \frac{|S_{21}|}{|S_{12}|}$, $K = \frac{1 + |\Delta|^2 - |S_{11}|^2 - |S_{22}|^2}{2\,|S_{12}\,S_{21}|}$, $\Delta = S_{11}\,S_{22} - S_{21}\,S_{12}$

MAG = Maximum Available Gain
MSG = Maximum Stable Gain

TYPICAL COMMON EMITTER SCATTERING PARAMETERS (T_A = 25°C)



Coordinates in Ohms
Frequency in GHz
(V_{CE} = 2.5 V, I_C = 3 mA)



NE68039

V_{CE} = 2.5 V, I_C = 3 mA

FREQUENCY	S11		S21		S12		S22		K	MAG[1]
(MHz)	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG		(dB)
50	0.935	-5.8	9.685	173.9	0.007	83.3	0.990	-3.7	0.11	31.4
100	0.903	-15.3	9.393	168.4	0.015	79.8	0.984	-6.0	0.10	28.0
200	0.826	-26.3	8.809	154.7	0.028	72.7	0.951	-11.7	0.25	25.0
300	0.770	-38.7	8.225	144.2	0.039	68.7	0.899	-16.2	0.31	23.2
400	0.690	-49.6	7.593	134.7	0.051	64.6	0.850	-19.6	0.40	21.7
500	0.618	-58.1	6.894	126.4	0.060	62.3	0.806	-21.9	0.48	20.6
600	0.545	-67.5	6.290	119.4	0.067	59.4	0.759	-24.0	0.56	19.7
800	0.436	-83.4	5.266	107.3	0.079	56.5	0.689	-26.3	0.70	18.2
1000	0.353	-98.2	4.489	98.4	0.089	56.3	0.638	-27.6	0.81	17.0
1500	0.232	-138.6	3.270	80.4	0.114	56.3	0.555	-31.2	0.99	14.6
2000	0.217	-177.0	2.573	66.5	0.138	57.7	0.502	-36.5	1.08	11.0
2500	0.262	154.2	2.148	54.6	0.168	57.2	0.456	-43.4	1.08	9.3
3000	0.314	136.1	1.860	44.2	0.201	56.8	0.423	-53.6	1.05	8.3

V_{CE} = 6 V, I_C = 3 mA

100	0.918	-10	8.888	168	0.001	81	0.989	-5	0.29	39.5
200	0.891	-22	8.546	158	0.003	76	0.981	-8	0.26	34.5
400	0.757	-41	7.606	141	0.024	71	0.915	-14	0.32	25.0
600	0.634	-55	6.430	125	0.045	65	0.822	-18	0.54	21.5
800	0.511	-68	5.638	115	0.057	62	0.757	-20	0.69	20.0
1000	0.405	-78	4.839	105	0.073	61	0.700	-22	0.80	18.2
2000	0.225	-136	2.601	77	0.121	59	0.583	-29	1.09	11.5
3000	0.242	145	2.033	50	0.171	58	0.499	-41	1.07	9.1
4000	0.359	117	1.655	31	0.226	54	0.434	-64	1.00	8.6
5000	0.452	101	1.370	14	0.282	47	0.423	-91	0.92	6.9
6000	0.536	91	1.172	0	0.340	41	0.420	-116	0.84	5.4

V_{CE} = 6 V, I_C = 10 mA

100	0.756	-21	20.155	156	0.001	122	0.945	-9	0.27	36.1
200	0.647	-40	17.163	140	0.001	82	0.887	-13	0.47	34.0
400	0.423	-65	12.024	118	0.009	71	0.774	-16	1.55	26.8
600	0.301	-77	8.762	104	0.019	68	0.691	-16	1.50	22.4
800	0.211	-92	6.962	97	0.035	68	0.643	-16	1.28	19.9
1000	0.143	-108	5.674	89	0.051	71	0.614	-17	1.18	17.9
2000	0.127	146	3.089	66	0.113	69	0.551	-24	1.09	12.5
3000	0.251	120	2.207	46	0.179	64	0.477	-37	1.01	10.3
4000	0.371	107	1.768	30	0.240	57	0.407	-60	0.94	8.7
5000	0.462	95	1.471	13	0.298	49	0.392	-88	0.87	6.9
6000	0.543	87	1.247	-1	0.354	41	0.389	-114	0.82	5.5

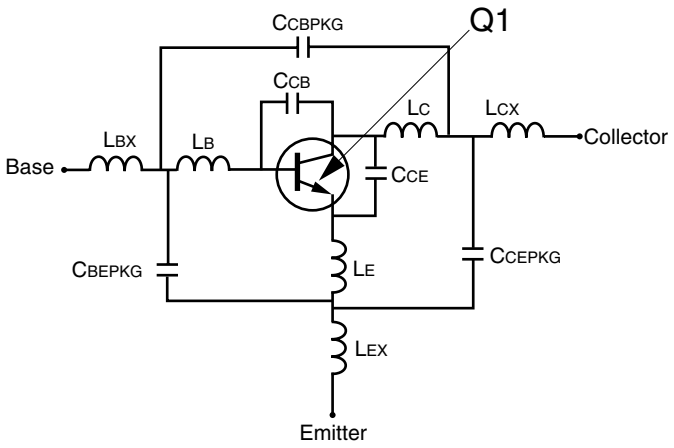
Note:
1.Gain Calculations:

$$MAG = \frac{|S_{21}|}{|S_{12}|}\left(K \pm \sqrt{K^2 - 1}\right)$$. When $K \leq 1$, MAG is undefined and MSG values are used. $$MSG = \frac{|S_{21}|}{|S_{12}|}$$, $$K = \frac{1 + |\Delta|^2 - |S_{11}|^2 - |S_{22}|^2}{2\,|S_{12}\,S_{21}|}$$, $\Delta = S_{11}\,S_{22} - S_{21}\,S_{12}$

MAG = Maximum Available Gain
MSG = Maximum Stable Gain

NE68018 NONLINEAR MODEL

SCHEMATIC



BJT NONLINEAR MODEL PARAMETERS (1)

Parameters	Q1	Parameters	Q1
IS	3.84e-16	MJC	0.64
BF	124.9	XCJC	0
NF	1.05	CJS	0
VAF	11.9	VJS	0.75
IKF	0.027	MJS	0
ISE	1.0e-14	FC	0.5
NE	2.17	TF	8.7e-12
BR	1	XTF	18
NR	1.05	VTF	19.1
VAR	Infinity	ITF	0.082
IKR	Infinity	PTF	0
ISC	0	TR	0.635e-9
NC	2	EG	1.11
RE	0.6	XTB	0
RB	17.9	XTI	3
RBM	1.02	KF	0
IRB	4.01e-4	AF	1
RC	10.46		
CJE	0.358e-12		
VJE	0.71		
MJE	0.5		
CJC	0.162e-12		
VJC	0.79		

(1) Gummel-Poon Model

UNITS

Parameter	Units
time	seconds
capacitance	farads
inductance	henries
resistance	ohms
voltage	volts
current	amps

ADDITIONAL PARAMETERS

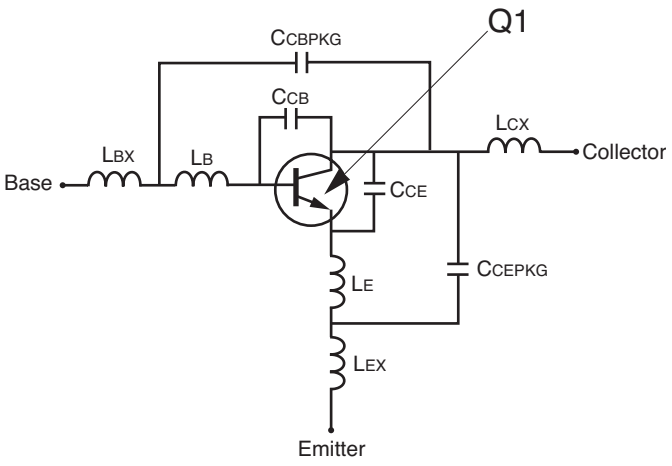
Parameters	68018
C_{CB}	0.08e-12
C_{CE}	0.08e-12
L_B	1.38e-9
L_C	2.55e-9
L_E	0.85e-9
C_{CBPKG}	0.14e-12
C_{CEPKG}	0.58e-12
C_{BEPK}	0.29e-12
L_{BX}	0.18e-9
L_{CX}	0.47e-9
L_{EX}	0.09e-9

MODEL RANGE

Frequency: 0.05 to 5.0 GHz
Bias: V_{CE} = 1 V to 6 V, I_C = 1 mA to 15 mA
Date: 5/31/96

NE68019 NONLINEAR MODEL

SCHEMATIC



BJT NONLINEAR MODEL PARAMETERS (1)

Parameters	Q1	Parameters	Q1
IS	3.84e-16	MJC	0.64
BF	124.9	XCJC	0
NF	1.05	CJS	0
VAF	11.9	VJS	0.75
IKF	0.027	MJS	0
ISE	1.0e-14	FC	0.5
NE	2.17	TF	8.7e-12
BR	1	XTF	18
NR	1.05	VTF	19.1
VAR	Infinity	ITF	0.082
IKR	Infinity	PTF	0
ISC	0	TR	0.635e-9
NC	2	EG	1.11
RE	0.6	XTB	0
RB	17.9	XTI	3
RBM	1.02	KF	0
IRB	4.01e-4	AF	1
RC	10.5		
CJE	0.358e-12		
VJE	0.71		
MJE	0.5		
CJC	0.162e-12		
VJC	0.79		

(1) Gummel-Poon Model

UNITS

Parameter	Units
time	seconds
capacitance	farads
inductance	henries
resistance	ohms
voltage	volts
current	amps

ADDITIONAL PARAMETERS

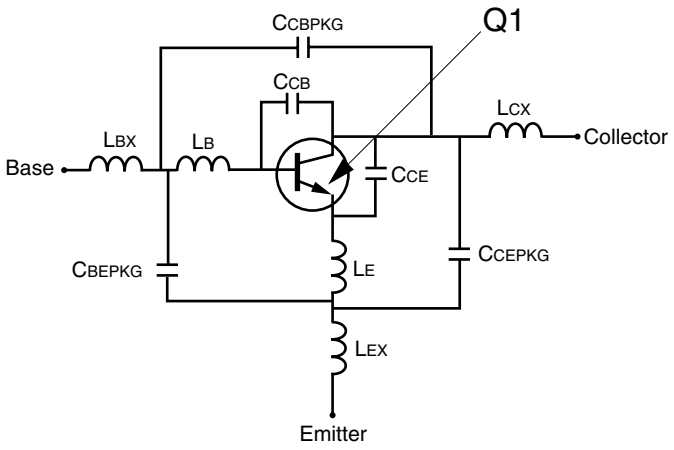
Parameters	68019
C_{CB}	0.08e-12
C_{CE}	0.08e-12
L_B	0.72e-9
L_E	0.76e-9
C_{CBPKG}	0.17e-12
C_{CEPKG}	0.21e-12
L_{BX}	0.19e-9
L_{CX}	0.19e-9
L_{EX}	0.19e-9

MODEL RANGE

Frequency: 0.05 to 3.0 GHz
Bias: V_{CE} = 1 V to 6 V, I_C = 1 mA to 15 mA
Date: 8/03

NE68030 NONLINEAR MODEL

SCHEMATIC



BJT NONLINEAR MODEL PARAMETERS (1)

Parameters	Q1	Parameters	Q1
IS	3.84e-16	MJC	0.64
BF	124.9	XCJC	0
NF	1.05	CJS	0
VAF	11.9	VJS	0.75
IKF	0.027	MJS	0
ISE	1.0e-14	FC	0.5
NE	2.17	TF	8.7e-12
BR	1	XTF	18
NR	1.05	VTF	19.1
VAR	Infinity	ITF	0.082
IKR	Infinity	PTF	0
ISC	0	TR	0.635e-9
NC	2	EG	1.11
RE	0.6	XTB	0
RB	17.9	XTI	3
RBM	1.02	KF	0
IRB	4.01e-4	AF	1
RC	10.5		
CJE	0.358e-12		
VJE	0.71		
MJE	0.5		
CJC	0.162e-12		
VJC	0.79		

(1) Gummel-Poon Model

UNITS

Parameter	Units
time	seconds
capacitance	farads
inductance	henries
resistance	ohms
voltage	volts
current	amps

ADDITIONAL PARAMETERS

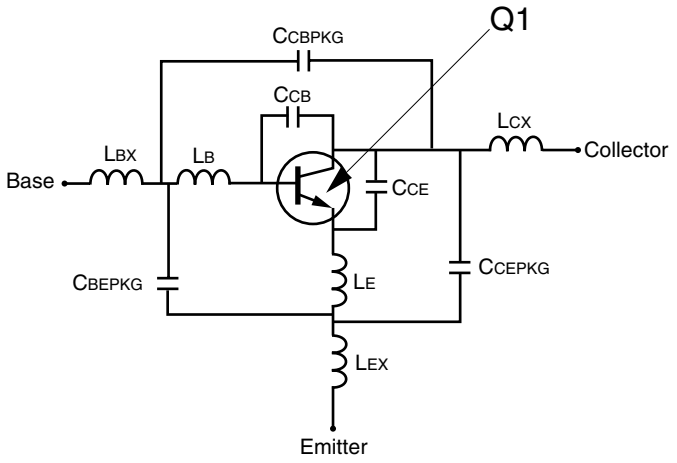
Parameters	68030
C_{CB}	0.08e-12
C_{CE}	0.08e-12
L_B	0.7e-9
L_E	1e-9
C_{CBPKG}	0.12e-12
C_{CEPKG}	0.16e-12
C_{BEPKG}	0.04e-12
L_{BX}	0.2e-9
L_{CX}	0.2e-9
L_{EX}	0.2e-9

MODEL RANGE

Frequency: 0.05 to 3.0 GHz
Bias: V_{CE} = 2.5 V to 6 V, I_C = 1 mA to 15 mA
Date: 10/25/96

NE68033 NONLINEAR MODEL

SCHEMATIC



BJT NONLINEAR MODEL PARAMETERS (1)

Parameters	Q1	Parameters	Q1
IS	3.84e-16	MJC	0.64
BF	124.9	XCJC	0
NF	1.05	CJS	0
VAF	11.9	VJS	0.75
IKF	0.027	MJS	0
ISE	1.0e-14	FC	0.5
NE	2.17	TF	8.7e-12
BR	1	XTF	18
NR	1.05	VTF	19.1
VAR	Infinity	ITF	0.082
IKR	Infinity	PTF	0
ISC	0	TR	0.635e-9
NC	2	EG	1.11
RE	0.6	XTB	0
RB	17.9	XTI	3
RBM	1.02	KF	0
IRB	4.01e-4	AF	1
RC	10.5		
CJE	0.358e-12		
VJE	0.71		
MJE	0.5		
CJC	0.162e-12		
VJC	0.79		

(1) Gummel-Poon Model

UNITS

Parameter	Units
time	seconds
capacitance	farads
inductance	henries
resistance	ohms
voltage	volts
current	amps

ADDITIONAL PARAMETERS

Parameters	68033
C_{CB}	0.08e-12
C_{CE}	0.08e-12
L_B	0.65e-9
L_E	0.95e-9
C_{CBPKG}	0.1e-12
C_{CEPKG}	0.1e-12
C_{BEPKG}	0.01e-12
L_{BX}	0.3e-9
L_{CX}	0.5e-9
L_{EX}	0.3e-9

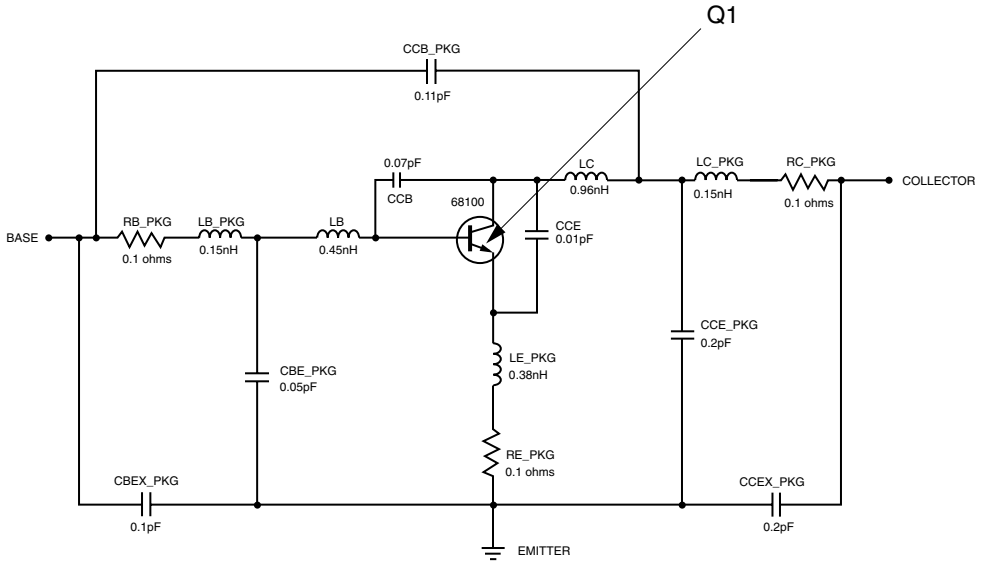
MODEL RANGE

Frequency: 0.05 to 3.0 GHz
Bias: V_{CE} = 2.5 V to 6 V, I_C = 0.3 mA to 20 mA
Date: 7/97

Note:
This nonlinear model utilized the latest data available. See our Design Parameter Library at **www.cel.com** for this data.

NE68035 NONLINEAR MODEL

SCHEMATIC



BJT NONLINEAR MODEL PARAMETERS (1)

Parameters	Q1	Parameters	Q1
IS	3.84e-16	MJC	0.64
BF	124.9	XCJC	0
NF	1.05	CJS	0
VAF	11.9	VJS	0.75
IKF	0.027	MJS	0
ISE	1.0e-14	FC	0.5
NE	2.17	TF	8.7e-12
BR	1	XTF	18
NR	1.05	VTF	19.1
VAR	Infinity	ITF	0.082
IKR	Infinity	PTF	0
ISC	0	TR	0.635e-9
NC	2	EG	1.11
RE	0.6	XTB	0
RB	17.9	XTI	3
RBM	1.02	KF	0
IRB	4.01e-4	AF	1
RC	10.5		
CJE	0.358e-12		
VJE	0.71		
MJE	0.5		
CJC	0.162e-12		
VJC	0.79		

(1) Gummel-Poon Model

UNITS

Parameter	Units
time	seconds
capacitance	farads
inductance	henries
resistance	ohms
voltage	volts
current	amps

MODEL RANGE

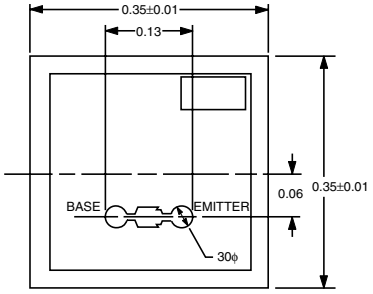
Frequency: 0.05 to 5.0 GHz

Bias: V_{CE} = 6 V, I_C = 5 mA to 20 mA

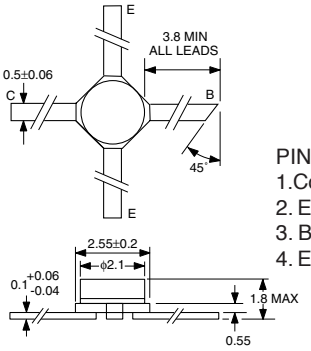
Date: 10/31/96

OUTLINE DIMENSIONS (Units in mm)

NE68000 (CHIP)
(Chip Thickness: 160 μm)

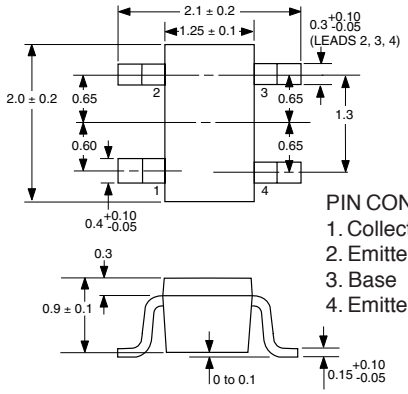


PACKAGE OUTLINE 35
(MICRO-X)



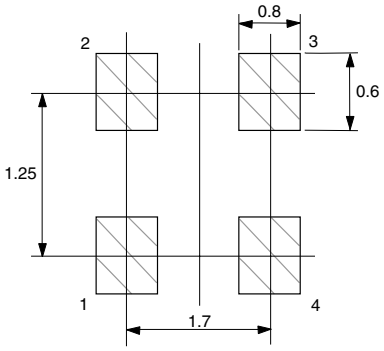
PIN CONNECTIONS
1.Collector
2. Emitter
3. Base
4. Emitter

PACKAGE OUTLINE 18

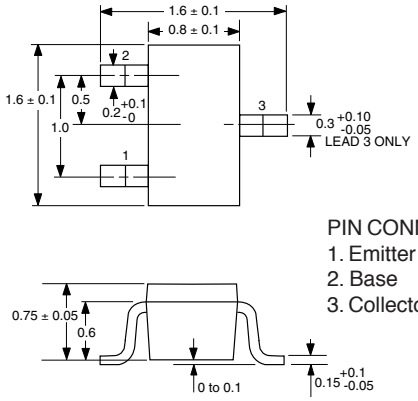


PIN CONNECTIONS
1. Collector
2. Emitter
3. Base
4. Emitter

PACKAGE OUTLINE 18
RECOMMENDED P.C.B. LAYOUT

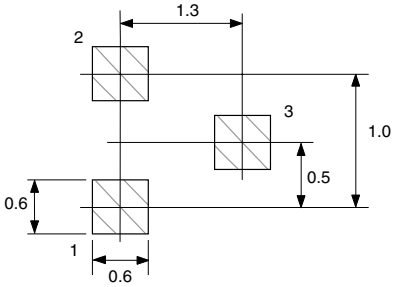


PACKAGE OUTLINE 19

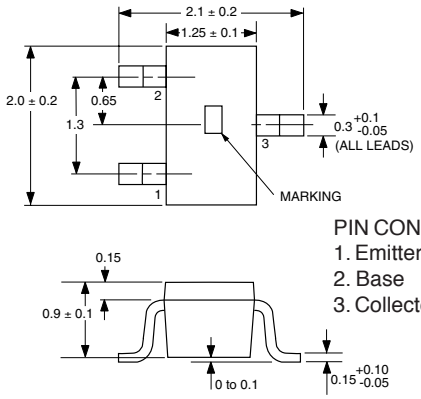


PIN CONNECTIONS
1. Emitter
2. Base
3. Collector

PACKAGE OUTLINE 19
RECOMMENDED P.C.B. LAYOUT

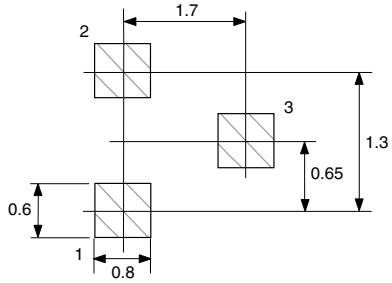


PACKAGE OUTLINE 30



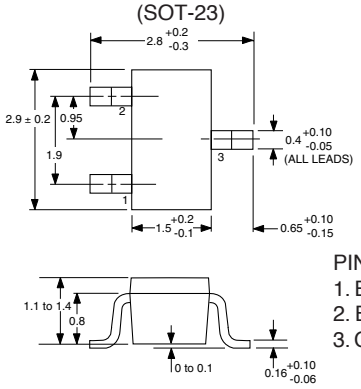
PIN CONNECTIONS
1. Emitter
2. Base
3. Collector

PACKAGE OUTLINE 30
RECOMMENDED P.C.B. LAYOUT



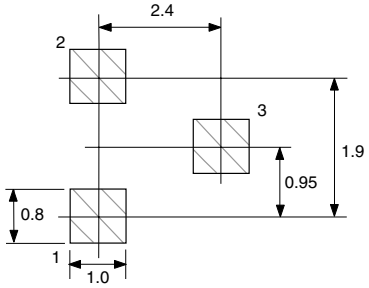
OUTLINE DIMENSIONS (Units in mm)

PACKAGE OUTLINE 33
(SOT-23)

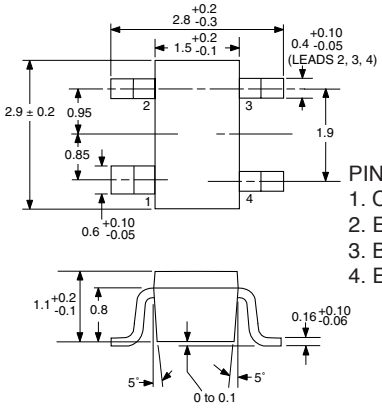


PIN CONNECTIONS
1. Emitter
2. Base
3. Collector

PACKAGE OUTLINE 33
RECOMMENDED P.C.B. LAYOUT

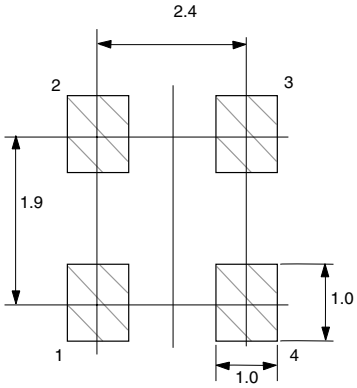


PACKAGE OUTLINE 39

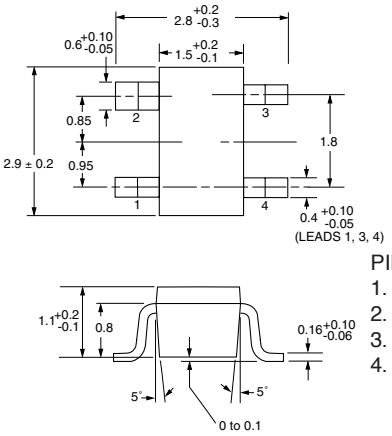


PIN CONNECTIONS
1. Collector
2. Emitter
3. Base
4. Emitter

PACKAGE OUTLINE 39
RECOMMENDED P.C.B. LAYOUT

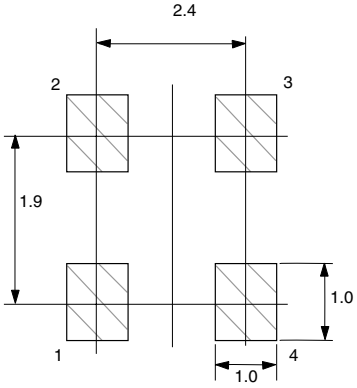


PACKAGE OUTLINE 39R



PIN CONNECTIONS
1. Emitter
2. Collector
3. Emitter
4. Base

PACKAGE OUTLINE 39
RECOMMENDED P.C.B. LAYOUT



ORDERING INFORMATION

PART NUMBER	QUANTITY	PACKAGING
NE68800	100	Waffle Pack
NE68018-T1-A[1]	3000	Tape & Reel
NE68019-T1-A[1]	3000	Tape & Reel
NE68030-T1-A[1]	3000	Tape & Reel
NE68033-T1B-A[1]	3000	Tape & Reel
NE68035	1	ESD Bag
NE68039-T1-A[1]	3000	Tape & Reel
NE68039R-T1	3000	Tape & Reel

Note:
1. Lead material: Cu
   Lead plating: SnBi - 2.5%Bi Typ.